



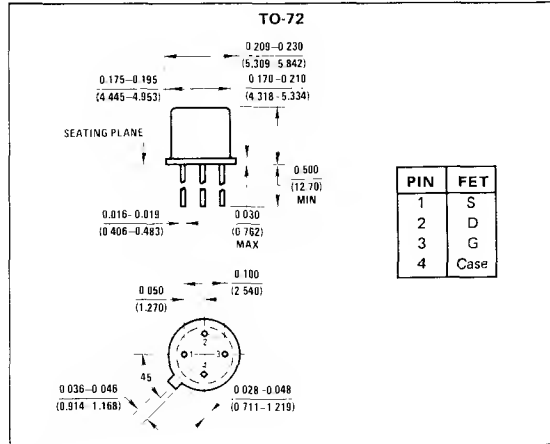
# 2N5397, 2N5398 N-Channel JFETs

## General Description

The 2N5397 thru 2N5398 series of N-channel JFETs is designed for VHF/UHF common-source or common-gate amplifiers, mixers and oscillators.

## Absolute Maximum Ratings (25°C)

Gate-Drain or Gate-Source Voltage	-25V
Gate Current	10 mA
Total Device Dissipation (Derate 1.7 mW/°C)	300 mW
Storage Temperature Range	-65°C to +200°C
Lead Temperature (1/16" from case for 10 seconds)	300°C



## Electrical Characteristics (25°C unless otherwise noted)

PARAMETER	CONDITIONS	2N5397		2N5398		UNITS	
		MIN	MAX	MIN	MAX		
I <sub>GSS</sub> Gate Reverse Current	V <sub>GS</sub> = -15V, V <sub>DS</sub> = 0 150°C		-0.1		-0.1	nA	
			-0.1		-0.1	µA	
BV <sub>GSS</sub> Gate-Source Breakdown Voltage	V <sub>DS</sub> = 0, I <sub>G</sub> = -1 µA	-25		-25		V	
V <sub>GS(off)</sub> Gate-Source Cutoff Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1 nA	-1.0	-6.0	-1.0	-6.0		
I <sub>DSS</sub> Saturation Drain Current	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	10	30	5	40	mA	
V <sub>GS(f)</sub> Gate-Source Forward Voltage	V <sub>DS</sub> = 0, I <sub>G</sub> = 1 mA		1		1	V	
g <sub>fs</sub> Common-Source Forward Transconductance, (Note 1)	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 1 kHz	6000	10,000			µmho
					5500	10,000	
g <sub>os</sub> Common-Source Output Conductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 1 kHz		200			µmho
						400	
C <sub>rss</sub> Common-Source Reverse Transfer Capacitance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 1 MHz		1.2			pF
						1.3	
C <sub>iss</sub> Common-Source Input Capacitance	V <sub>DG</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 1 MHz		5.0			pF
						5.5	
g <sub>iss</sub> Common-Source Input Conductance	V <sub>DG</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 450 MHz		2000			µmho
						3000	
g <sub>oss</sub> Common-Source Output Conductance	V <sub>DG</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 450 MHz		400			µmho
						500	
g <sub>fs</sub> Common-Source Forward Transconductance, (Note 1)	V <sub>DG</sub> = 10V, I <sub>D</sub> = 10 mA V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0	f = 450 MHz	5500	9000			µmho
					5000	10,000	
G <sub>ps</sub> Common-Source Power Gain (Neutralized)	V <sub>DG</sub> = 10V, I <sub>D</sub> = 10 mA		15			dB	
NF Common-Source, Spot Noise Figure (Neutralized)	V <sub>DG</sub> = 10V, I <sub>D</sub> = 10 mA		3.5			dB	

Note 1: Pulse test duration = 2 ms.